

## NDIA 55<sup>th</sup> Annual Fuze Conference



TECHNOLOGY DRIVEN. WARFIGHTER FOCUSED.

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- •This paper will present my views and recent experience working with the FESWG to study the use of Programmable Logic Devices in fuzes.
- •Present data gathered by the FESWG and other sources will be presented.
- Being a fuze designer and also a member of the Army Fuze Safety Board gives me a unique viewpoint on this issue.





Background



#### Programmable Logic Devices (PLD) are essential tools to the fuze designer



• PLD's enable advanced fuzes to perform complex and precisely timed functions, measure environments, communicate with other subsystems, etc

• PLD's are used in large percentage of electronic

fuzes







 PLD's that use charge based memory cell technology are rapidly replacing PLD's that use fixed "fusible type " memory cells

SUC

- In particular newer model PLD's which have improved performance such as reduced power consumption are only available in the charged based memory cell technology
- PLD vendors claim long memory retention time for charged based memory cells (ex: 40 years)
- Basic question for the fuze safety community Can we rely on these devices in safety critical fuze circuits and if so what are the guidelines for their use?







- To date only fusible type FPGA's or OTP type microcontrollers have been approved by Fuze Safety Boards
- The FESWG created a subcommittee in 2009 to study the use of PLD's in fuze circuits.
  - Main question to be answered :

"Is there an acceptable way to use PLD's that use charge based memory technology in safety critical fuze circuits?"





Fuze Life and PLD Memory Loss



# Good (In circuit tests)



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Is memory still good???



- Any fuze part can fail for a number of reasons and in general fuzes are designed to stay safe if a single point failure occurs.
- However if there is an inherent memory loss failure mechanism in a PLD, a significant number of fuzes could experience failures during long term storage.
- The software code would fail randomly and the PLD's performance could become unpredictable.
- Overall system safety would be degraded.





- Tasked Sandia NL under the DOD/DOE TCG program to assess the validity of vendors memory retention claims
- Studied potential circuit techniques and guidelines that could mitigate the effects of PLD memory loss on safety
- Initiated an update of the FESWG Logic devices guidelines







- Sample PLD's were tested by Sandia NL's in an attempt to verify vendors memory retention claims
- Two flash microcontrollers and an FPGA's were selected for test
- The following tests were conducted:
  - Unpowered HAST/130C
  - Temperature Cycling@-55 to +150C
  - High Temp Storage @ 150C





### **Summary of Data Retention Test Results**



	HAST unpowered	Temp Cycling -55/+150C	Data Retention
FPGA	2 wire bond failures in 300- 400 hrs	0 Failures 1500/2000 cycles	0 failures 3000 hrs@150C
Micro 1	0 failures in 350 hrs	0 failures 1000/1500 cycles	0 failures 3000 hrs@150C
Micro 2	N/A	N/A	0 failures 8000 hrs@150C



# No memory cell failures!





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## **Memory Check Concept**

(Hubal Key)





Fuze Safety Critical Functions Locked in here.

Now what was that combination again??





# 1 1 0 0 1 0 1 1 0 0 1 1 0 0 1 1 0 0 1



PLD has to derive the right combination based on checking it's memory.

This value is not resident in memory

The memory check is robust and the value is unlikely to be generated by mistake.*TECHNOLOGY DRIVEN. WARFIGHTER FOCUSED*.



## **Hubal Key Diagram**





Purpose:

Checks program memory against an external "coded word" (a.k.a. key).

Re-programmability feature shall be defeated robustly (Service-review required).

Hubal Key acts only as a check for the integrity of EPROM/EEPROM/Flash memory.

Hubal Key does not check hardware or processing functions.

Lines between  $\mu$ C and Hubal Key are dedicated and shall not be used for any other purposes, including monitoring.

Memory integrity check shall be run upon the application of power and at the start of all arming processes.

## **Concept for In-Circuit Check of PLD Memory**







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Compares micro's 16 bits to

stored Hubal "key" code

(65k possible combos)





Advantage : Fast – simple processing Disadvantage : doubles memory size





- Takes extra electronic parts to implement.
- More applicable to micro's, fpga's not as straightforward.
  - Can be implemented in a custom IC or by a small discrete SMD ckt
- It takes time to conduct the memory check this may cause a problem for some systems that have to arm quickly (ex: APS & high velocity close engagement rounds).
- Memory loss still results in a fuze dud





## Sample Time to Conduct a CRC check



Example 5. Assembly Language for CRC-16 Using a Lookup Table

crc\_lo data 40h ; any direct address is okay

crc\_hi data 41h tmp data 42h

#### MAXIM APPLICATION NOTES

; CRC16 subroutine.

- ; accumulator is assumed to have byte to be crc'ed
- ; three direct variables are used, tmp, crc\_hi and crc\_lo

- ; crc\_hi and crc\_lo contain the CRC16 result
- ; this CRC16 algorithm uses a table lookup

#### crc16:

xrl a, crc\_lo; create index into tables mov tmp, a; save index push dph; save dptr push dpl; mov dptr, #crc16\_tablo; low part of table address movc a, @a+dptr; get low byte xrl a, crc\_hi; mov crc\_lo, a; save of low result mov dptr, #crc16\_tabhi; high part of table address mov a, tmp; index movc a, @a+dptr; mov crc\_hi, a; save high result pop dpl; restore pointer pop dph; ret; all done with calculation



Sample computation time calc. for 16 bit crc check:

Assumptions

**4 Mhz clock** (typ internal clock freq. )

4 clock cycles /instruction – typ for Microchip parts

#### 4k of tactical code

15 instructions for 2 bytes of memory check



1 usec per intruction x 15 instructions x 4k/2 =

## 30 msec +

Note: A lookup table with crc values must be stored in memory for this program



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- SOPM ESAD Safety Architectures makes use of a charged based device due to size constraints.
- Implementing CRC 16 verification of stored memory
  - Charged based device interfaces with dedicated discrete circuitry via two pins.
  - Compares expected hardwired known CRC bit-by-bit against device's memory.
  - Check occurs first, at power up.
  - Power shut down of the device occurs if:
    - Mis-match occurs
    - More than 16 bits are clocked out
    - Less than 16 bits are clocked in fixed time frame
- Active components includes a combination of shift registers, counters, and timers.
- Minimal board real estate impact.
  - Projected to be not more than 260 mm<sup>2</sup> or 0.4 in<sup>2</sup> of layout space.



Summary



- The FESWG Logic Devices tech manual has been updated to address use of charged based PLD's and include memory checking
  - Looking for feedback from the fuze industry
- More study of PLD's needed
  - Additional memory retention tests to increase confidence level
  - Develop an understanding of failure mechanisms and possible screening techniques
- Almost certainly new technologies will emerge that the fuze safety community will have to deal with





